

First principles based study of the dependence of Fermi Level Pinning on semiconductor surface orientation

Initial Investigation

» First principles based study

- Surface energetics of clean, unreconstructed surfaces.
- Initial chemisorption pathway of ALD based oxide deposition.
- ✓ Surface dependent defect formation energies.
- ✓ Composite D.O.S.

Initial results (GaAs)

- » (110) clean surface most stable energetically.
- » H passivation unfavorable, OH passivation favorable energetically
- » (111)B adsorbs Al(CH3)3 'better' than (111)A – cue Self Cleaning effect?





